

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 7,018,696 B2
APPLICATION NO. : 10/825779
DATED : March 28, 2006
INVENTOR(S) : Han H. Nee

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

In column 3, line 50, please change "approximately 0.3, to 1.4 microns." to --approximately 0.3 to 1.4 microns.--

In column 36, line 23, please change "The optical storage medium of claim 19," to --The optical storage medium of claim 18,--

In column 37, line 30, please change "in the metal alloy is defined by $Ag_xCu_zA_w$ " to --in the metal alloy is defined by $Ag_xCu_zA_w$ --

In column 39, line 28, please change "In-Se-Tl, In Sb, In-S-Se," to --In-Se-Tl, In Sb, In-Sb-Se,--

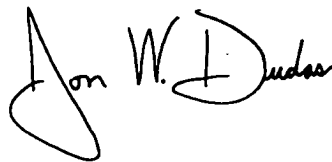
In column 40, line 39, please change "The optical storage medium of claim 30," to --The optical storage medium of claim 81,--

In column 40, line 41, please change "The optical storage medium of claim 30," to --The optical storage medium of claim 81,--

In column 40, line 43, please change "The optical storage medium of claim 30," to --The optical storage medium of claim 81,--

Signed and Sealed this

Twenty-fifth Day of November, 2008



JON W. DUDAS
Director of the United States Patent and Trademark Office